

Vishay Semiconductors

AUTOMOTIVE

COMPLIANT

GREEN

(5-2008)

# High Speed Infrared Emitting Diodes, 890 nm, GaAlAs, DH



# DESCRIPTION

VSMF2893X01 series are infrared, 890 nm emitting diodes in GaAlAs (DH) technology with high radiant power and high speed, molded in clear, untinted plastic packages (with lens) for surface mounting (SMD).

#### **FEATURES**

Package type: surface mount

· Package form: GW, RGW

• Dimensions (L x W x H in mm): 2.3 x 2.3 x 2.55

AEC-Q101 qualified

Peak wavelength: λ<sub>p</sub> = 890 nm

High reliability

· High radiant power

High radiant intensity

• Angle of half intensity:  $\varphi = \pm 25^{\circ}$ 

· Low forward voltage

• Suitable for high pulse current operation

• Terminal configurations: gullwing or reserve gullwing

 Package matches with detector VEMD2xx3X01 and VEMT2xx3X01 series

Floor life: 4 weeks, MSL 2a, acc. J-STD-020

 Material categorization: For definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **APPLICATIONS**

- IrDA compatible data transmission
- 3D TV
- IR touch panels
- · Miniature light barrier
- Photointerrupters
- · Optical switch
- · Shaft encoders
- IR emitter source for proximity applications

PRODUCT SUMMARY				
COMPONENT	I <sub>e</sub> (mW/sr)	φ (deg)	λ <sub>p</sub> (nm)	t <sub>r</sub> (ns)
VSMF2893RGX01	20	± 25	890	30
VSMF2893GX01	20	± 25	890	30

#### Note

• Test conditions see table "Basic Characteristics"

ORDERING INFORMATION				
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM	
VSMF2893RGX01	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Reverse gullwing	
VSMF2893GX01	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Gullwing	

#### Note

MOQ: minimum order quantity



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<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		V <sub>R</sub>	5	V
Forward current		I <sub>F</sub>	100	mA
Peak forward current	$t_p/T = 0.5, t_p = 100 \mu s$	I <sub>FM</sub>	200	mA
Surge forward current	t <sub>p</sub> = 100 μs	I <sub>FSM</sub>	1	Α
Power dissipation		P <sub>V</sub>	160	mW
Junction temperature		T <sub>j</sub>	100	°C
Operating temperature range		T <sub>amb</sub>	- 40 to + 85	°C
Storage temperature range		T <sub>stg</sub>	- 40 to + 100	°C
Soldering temperature	Acc. figure 9, J-STD-020	T <sub>sd</sub>	260	°C
Thermal resistance junction/ambient	J-STD-051, leads 7 mm, soldered on PCB	R <sub>thJA</sub>	250	K/W

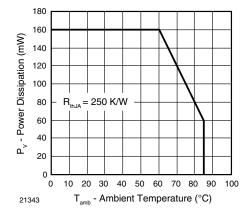


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

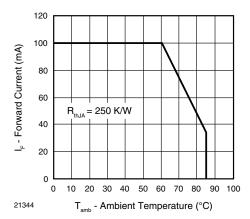


Fig. 2 - Forward Current Limit vs. Ambient Temperature

<b>BASIC CHARACTERSITICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Converd veltage	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	V <sub>F</sub>	1.25	1.4	1.6	V
Forward voltage	$I_F = 1 \text{ A}, t_p = 100 \mu \text{s}$	V <sub>F</sub>		2.3		V
Tanada a la constitución de la CM	I <sub>F</sub> = 1 mA	TK <sub>VF</sub>		- 1.8		mV/K
Temperature coefficient of V <sub>F</sub>	I <sub>F</sub> = 100 mA	TK <sub>VF</sub>		- 1.1		mV/K
Reverse current	V <sub>R</sub> = 5 V	I <sub>R</sub>			10	μΑ
Junction capacitance	$V_R = 0 \text{ V}, f = 1 \text{ MHz}, E = 0 \text{ mW/cm}^2$	CJ		125		pF
Dadient intensity	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	l <sub>e</sub>	10	20	30	mW/sr
Radiant intensity	$I_F = 1 \text{ A}, t_p = 100 \mu \text{s}$	l <sub>e</sub>		180		mW/sr
Radiant power	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	фe		40		mW
Temperature coefficient of $\phi_{e}$	I <sub>F</sub> = 100 mA	TKφ <sub>e</sub>		- 0.35		%/K
Angle of half intensity		φ		± 25		deg
Peak wavelength	I <sub>F</sub> = 30 mA	λρ	870	890	910	nm
Spectral bandwidth	I <sub>F</sub> = 30 mA	Δλ		40		nm
Temperature coefficient of $\lambda_p$	I <sub>F</sub> = 30 mA	TKλ <sub>p</sub>		0.25		nm/K
Rise time	I <sub>F</sub> = 100 mA, 20 % to 80 %	t <sub>r</sub>		30		ns
Fall time	I <sub>F</sub> = 100 mA, 20 % to 80 %	t <sub>f</sub>		30		ns
Cut-off frequency	I <sub>DC</sub> = 70 mA, I <sub>AC</sub> = 30 mA pp	f <sub>c</sub>		12		MHz

# Vishay Semiconductors

### **BASIC CHARACTERSITICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

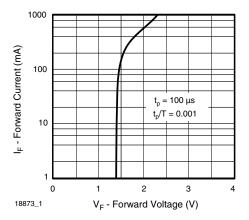


Fig. 3 - Forward Current vs. Forward Voltage

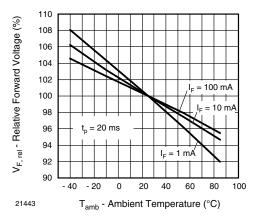


Fig. 4 - Relative Forward Voltage vs. Ambient Temperature

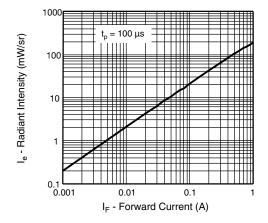


Fig. 5 - Radiant Intensity vs. Forward Current

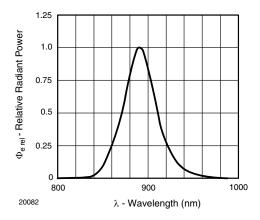


Fig. 6 - Relative Radiant Power vs. Wavelength

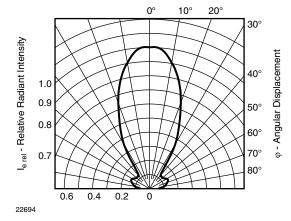


Fig. 7 - Relative Radiant Intensity vs. Angular Displacement

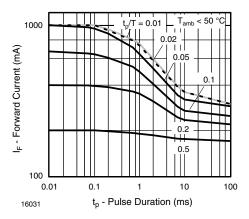


Fig. 8 - Pulse Forward Current vs. Pulse Duration

## Vishay Semiconductors

#### **SOLDER PROFILE**

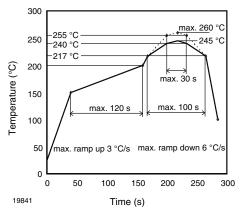


Fig. 9 - Lead (Pb)-free Reflow Solder Profile acc. J-STD-020

#### **DRYPACK**

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

#### **FLOOR LIFE**

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label:

Floor life: 4 weeks

Conditions: T<sub>amb</sub> < 30 °C, RH < 60 %

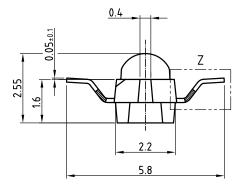
Moisture sensitivity level 2a, acc. to J-STD-020.

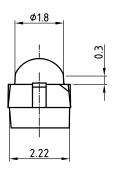
#### **DRYING**

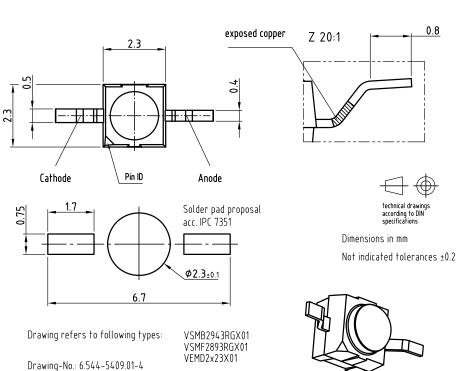
In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40  $^{\circ}$ C (+ 5  $^{\circ}$ C), RH < 5  $^{\circ}$ M.

#### PACKAGE DIMENSIONS in millimeters: VSMF2893RGX01

Issue: prel. 03.08.12

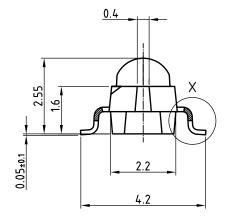


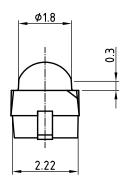


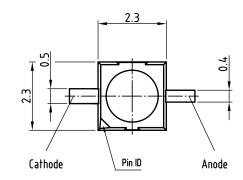


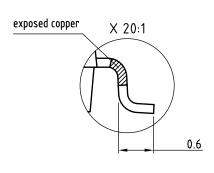
# Vishay Semiconductors

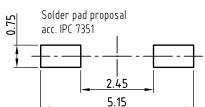
### PACKAGE DIMENSIONS in millimeters: VSMF2893GX01













Not indicated tolerances ±0.2

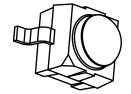
Drawing refers to following types:

VSMB2943GX01

VSMF2893GX01 VEMD2x23X01

Drawing-No.: 6.544-5408.01-4

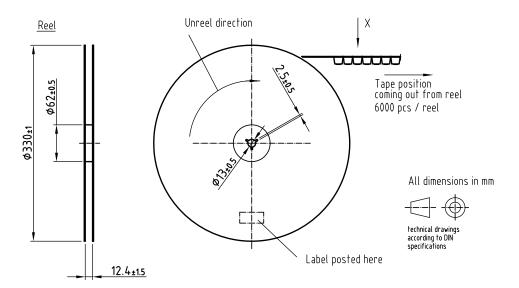
Issue: prel; 03.08.12



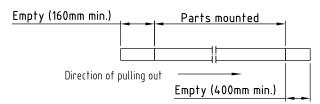
Dimensions in mm

# Vishay Semiconductors

### TAPING AND REEL DIMENSIONS in millimeters: VSMF2893RGX01

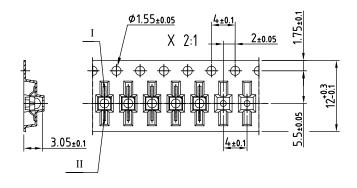


#### Leader and trailer tape:



#### Terminal position in tape

Lead I	Lead II
	read II
Calbada	Anode
carnoue	Alloue
Collector	Emitter
collector	CIIII I EI
Anode	Cathode
	Cathode Collector Anode



Drawing refers to following types: Reel dimensions and tape

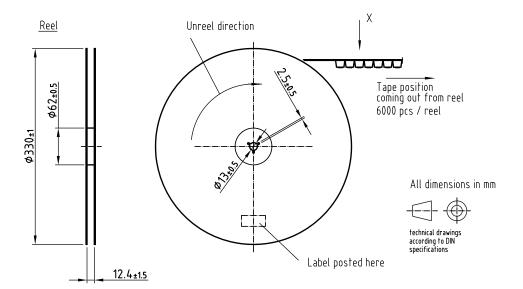
see table

Drawing-No.: 9.800-5100.02-4 Issue: prel; 03.08.12

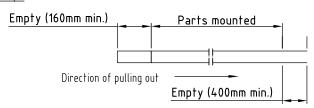


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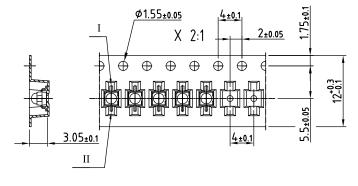
### TAPING AND REEL DIMENSIONS in millimeters: VSMF2893GX01



Leader and trailer tape:



Terminal position in tape				
Device	Lead I	Lead II		
VSMB2943GX01				
VSMF2893GX01	1			
VEMD2x23X01	Cathode	Anode		
VEMT2x23X01	Collector	Emitter		
	Collector	cillitei		
VCMV28E3G	Anode	Cathode		



Drawing refers to following types: see table Reel dimensions and tape Drawing-No.: 9.800-5091.21-4 Issue: prel; 03.08.12



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